## <u>Chapter Two</u>

#### ELECTROSTATIC POTENTIAL AND CAPACITANCE

(Prepared by AYYAPPAN C, HSST, GMRHSS KASARAGOD) ELECTROSTATIC POTENTIAL

• The electrostatic potential (*V*) at any point is the work done in bringing a unit positive charge from infinity to that point.

$$V = \frac{W}{q}$$
, W – work done, q – charge.

- Also W = qV
- It is a scalar quantity.
- Unit is J/C or volt (V)

## POTENTIAL DUE TO A POINT CHARGE



 The force acting on a unit positive charge (+1 C) at A , is

$$F = \frac{1}{4\pi\varepsilon_0} \frac{q \times 1}{x^2} = \frac{1}{4\pi\varepsilon_0} \frac{q}{x^2}$$

• Thus the work done to move a unit positive charge from A to B through a displacement dx is

$$dW = -\frac{1}{4\pi\varepsilon_0} \frac{q}{x^2} dx$$

- The negative sign shows that the work is done against electrostatic force.
- Thus the total work done to bring unit charge from infinity to the point P is

$$W = \int_{\infty}^{r} dW = \int_{\infty}^{r} \left[ -\frac{1}{4\pi\varepsilon_0} \frac{q}{x^2} dx \right]$$
$$W = -\frac{q}{4\pi\varepsilon_0} \int_{\infty}^{r} \left[ \frac{1}{x^2} dx \right]$$

Integrating

$$W = \frac{q}{4\pi\varepsilon_0} \left[ \frac{1}{r} - \frac{1}{\infty} \right] = \frac{q}{4\pi\varepsilon_0}$$

• Therefore electrostatic potential is given by

$$V = \frac{1}{4\pi\varepsilon_0} \frac{q}{r}$$

# Variation of potential V with r



### **Capacitor**

- It is a charge storing device.
- A capacitor is a system of two conductors separated by an insulator.



• A capacitor with large capacitance can hold large amount of charge *Q* at a relatively small *V*.

### **Capacitance**

- The potential difference is proportional to the charge , Q.
- Thus  $C = \frac{Q}{V}$
- The constant C is called the *capacitance of the capacitor. C is independent* of *Q or V.*
- The capacitance *C* depends only on the geometrical configuration (shape, size, separation) of the system of two conductors
- SI unit of capacitance is farad.
- Other units are,  $1 \mu F = 10^{-6} F$ ,  $1 nF = 10^{-9} F$ ,  $1 pF = 10^{-12} F$ , etc.

## Symbol of capacitor

#### Fixed capacitance





### **Dielectric strength**

- The maximum electric field that a dielectric medium can withstand without break-down is called its dielectric strength.
- The dielectric strength of air is about  $3 \times 10^{6} \text{ Vm}^{-1}$ .

### THE PARALLEL PLATE CAPACITOR

 A parallel plate capacitor consists of two large plane parallel conducting plates separated by a small distance

### Capacitance of parallel plate capacitor

- Let *A* be the area of each plate and *d* the separation between them.
- The two plates have charges Q and -Q.
- Plate 1 has surface charge density  $\sigma = Q/A$ and plate 2 has a surface charge density  $-\sigma$ .



At the region I and II, E=0

$$E = \frac{\sigma}{2\varepsilon_0} - \frac{\sigma}{2\varepsilon_0} = 0$$

• At the inner region

$$E = \frac{\sigma}{2\varepsilon_0} + \frac{\sigma}{2\varepsilon_0} = \frac{\sigma}{\varepsilon_0} = \frac{Q}{\varepsilon_0 A}$$

- The direction of electric field is from the positive to the negative plate.
- For a uniform electric field the potential difference is

$$V = E d = \frac{1}{\varepsilon_0} \frac{Qd}{A}$$

• The capacitance *C* of the parallel plate capacitor is then

$$C = \frac{Q}{V} = = \frac{\varepsilon_0 A}{d}$$

Thus 
$$C = \frac{\varepsilon_0 A}{d}$$



### <u>Combination of capacitors</u> <u>Capacitors in series</u>



- In series charge is same and potential is different on each capacitors.
- The total potential drop V across the combination is

$$V = V_1 + V_2$$

• Considering the combination as an effective capacitor with charge *Q* and potential difference *V*, we get

$$\frac{Q}{C} = \frac{Q}{C_1} + \frac{Q}{C_2}$$

• Therefore effective capacitance is

$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2}$$

• For n capacitors in series

$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2} + \dots + \frac{1}{C_n}$$

### **Capacitors in parallel**



- In parallel the charge is different, potential is same on each capacitor.
- The charge on the equivalent capacitor is  $Q = Q_1 + Q_2$
- Thus  $CV = C_1V + C_2V$
- Therefore  $C = C_1 + C_2$
- In general , for n capacitors  $C = C_1 + C_2 + \dots + C_n$

#### **Energy stored in a capacitor**

• Energy stored in a capacitor is the **electric potential energy.** 



- Charges are transferred from conductor 2 to conductor 1 bit by bit, so that at the end, conductor 1 gets charge *Q*.
- Work done to move a charge dq from conductor 2 to conductor 1, is dW = Potential × Charg e
- That is  $dW = \frac{q}{C} \times dq$
- Since potential at conductor 1 is , q/C.
- Thus the total work done to attain a charge Q on conductor 1, is

$$W = \int_{0}^{Q} dW = \int_{0}^{Q} \frac{q}{C} \times dq$$

• On integration we get,

$$W = \frac{1}{C} \left[ \frac{q^2}{2} \right]_0^0 = \frac{Q^2}{2C}$$

- This work is stored in the form of potential energy of the system.
- Thus energy stored in the capacitor is

$$U = \frac{Q^2}{2C}$$

• Also 
$$U = \frac{1}{2}QV$$
 or  $U = \frac{1}{2}CV^2$ 

### Alternate method

• We have the Q – V graph of a capacitor,



• Energy = area under the graph

• Thus, 
$$U = \frac{1}{2} \times Q \times V$$

• Also 
$$U = \frac{1}{2}CV^2$$

#### Energy Density of a capacitor

- Energy density is the energy stored per unit volume.
- We have  $U = \frac{Q^2}{2C}$

• But 
$$Q = \sigma A$$
 and  $C = \frac{\varepsilon_0 A}{d}$ 

• Thus we get 
$$U = \frac{(\sigma A)^2}{2} \left(\frac{d}{\varepsilon_0 A}\right)^2$$

• Using 
$$E = \frac{\sigma}{\varepsilon_0}$$
, we get  
 $U = \frac{1}{2}\varepsilon_0 E^2 \times Ad$ 

• Thus energy per unit volume is given by  $\frac{U}{U} - \frac{1}{2} \epsilon F^2$ 

\*\*\*\*

$$\frac{1}{Ad} = \frac{1}{2}\varepsilon_0 E^2$$

• That is the energy density of the capacitor is

$$u = \frac{1}{2}\varepsilon_0 E^2$$

